



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Features

- Extremely high speed performance
- Blocks high voltages and currents
- Two TBU® protectors in one small package
- Simple, superior circuit protection
- Minimal PCB area
- RoHS compliant*, UL Recognized



Bourns® Model P850-G Series TBU® HSPs are not recommended for POTS applications. This series is suited for applications requiring a dual bidirectional device where 50 ohms of series resistance is acceptable. For new SLIC applications, we recommend that customers evaluate our [TBU-PL Series](#).

P850-G Series Dual TBU® High-Speed Protectors

Transient Blocking Units - TBU® Devices

Bourns® Model P850-G TBU® products are dual high-speed bidirectional protection components, constructed using MOSFET semiconductor technology, designed to protect against faults caused by short circuits, AC power cross, induction and lightning surges.

The TBU® high speed protector, triggering as a function of the MOSFET, blocks surges and provides an effective barrier behind which sensitive electronics are not exposed to large voltages or currents during surge events. The TBU® device is provided in a surface mount DFN package and meets industry standard requirements such as RoHS and Pb Free solder reflow profiles.

Agency Approval

UL recognized component File # E315805.

Industry Standards

Description			Model
Telcordia	GR-1089	Port Type 3, 5	P850-G
ITU-T	K.20, K.20E, K.21, K.21E, K.45		P850-G

Absolute Maximum Ratings ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

Symbol	Parameter	Value	Unit
V_{imp}	Maximum protection voltage for impulse faults with rise time $\geq 1\text{ }\mu\text{sec}$	850	V
V_{rms}	Maximum protection voltage for continuous V_{rms} faults	425	V
T_{op}	Operating temperature range	-40 to +85	$^{\circ}\text{C}$
T_{stg}	Storage temperature range	-65 to +150	$^{\circ}\text{C}$

Electrical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

Symbol	Parameter	Model	Min.	Typ.	Max.	Unit
I_{op}	Maximum current through the device that will not cause current blocking	P850-G120-WH P850-G200-WH			100 200	mA
$I_{trigger}$	Typical current for the device to go from normal operating state to protected state	P850-G120-WH P850-G200-WH		150 275		mA
I_{out}	Maximum current through the device	P850-G120-WH P850-G200-WH			200 400	mA
R_{device}	Series resistance of the TBU® device			50	55	Ω
R_{bal}	Line-to-line series resistance difference between two TBU® devices				2	Ω
t_{block}	Maximum time for the device to go from normal operating state to protected state				1	μs
$I_{quiescent}$	Current through the triggered TBU® device with 50 Vdc circuit voltage			0.7		mA
V_{reset}	Voltage below which the triggered TBU® device will transition to normal operating state			22		V

The P-G series TBU® devices are bidirectional; specifications are valid in both directions.

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

Applications

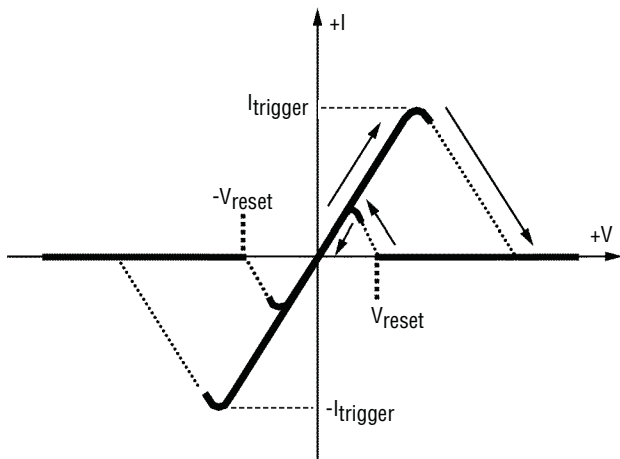
- Sensor protection
- Signal line protection

P850-G Series Dual TBU® High-Speed Protectors

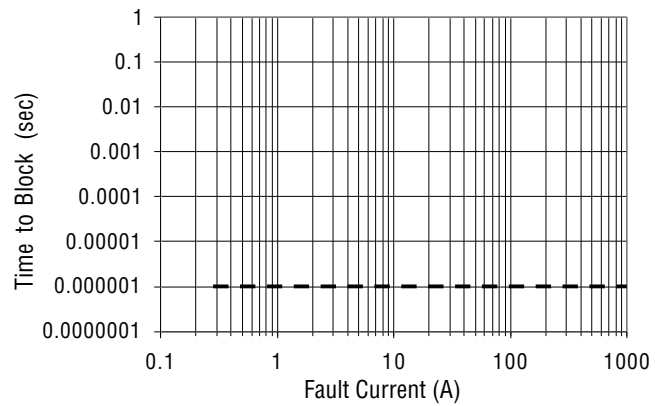
BOURNS®

Typical Performance Characteristics

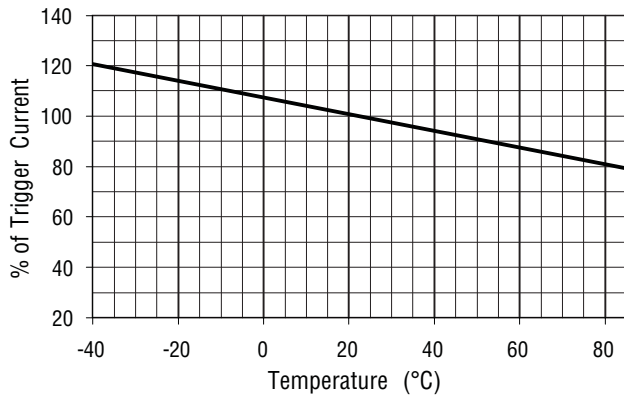
V-I Characteristics



Time to Block vs. Fault Current



Trigger Current Temperature



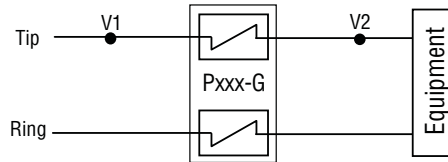
P850-G Series Dual TBU® High-Speed Protectors

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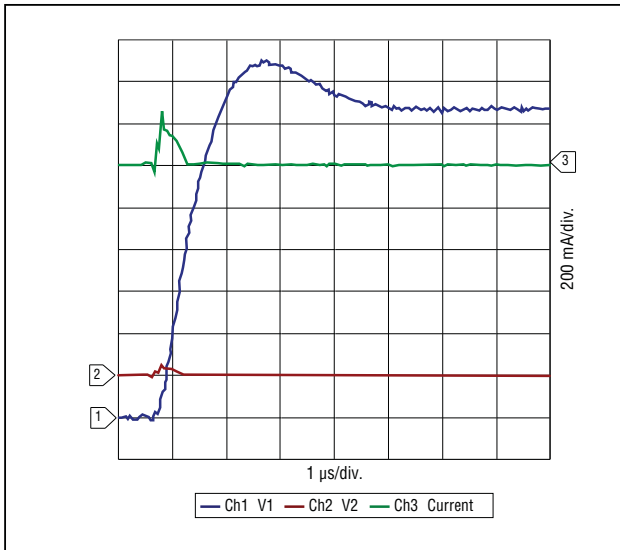
Operational Characteristics

The graphs below demonstrate the operational characteristics of the TBU® device. For each graph the fault voltage, protected side voltage, and current is presented.

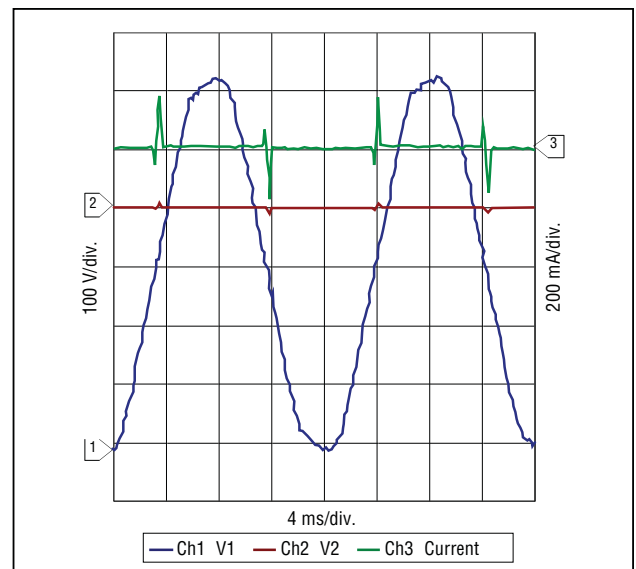
TEST CONFIGURATION DIAGRAM



P850-G Lightning, 850 V



P850-G Power Fault, 230 Vrms, 25 A



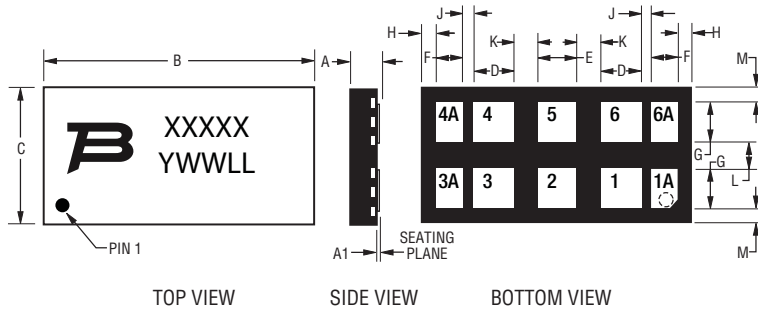
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P850-G Series Dual TBU® High-Speed Protectors

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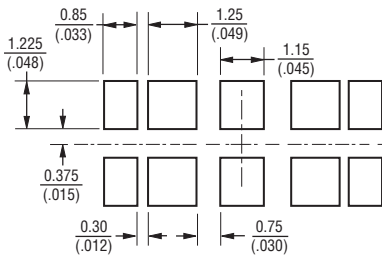
Product Dimensions



Pads 1A and 1 are internally connected; the same for pads 3A with 3, 4A with 4, and 6A with 6. This allows for one PCB layout to accommodate the Model P850.

Dim.	P850-G		
	Min.	Typ.	Max.
A	0.80 (.031)	0.90 (.035)	1.00 (.039)
A1	0.00 (.000)	0.025 (.001)	0.05 (.002)
B	8.15 (.321)	8.25 (.325)	8.35 (.329)
C	3.90 (0.154)	4.00 (0.157)	4.10 (0.161)
D	1.15 (.045)	1.25 (.049)	1.35 (.053)
E	1.05 (.041)	1.15 (.045)	1.25 (.049)
F	0.725 (.029)	0.825 (.032)	0.925 (.036)
G	1.10 (.043)	1.20 (.047)	1.30 (.051)
H	0.375 (.015)	0.425 (.017)	0.475 (.019)
J	0.25 (.010)	0.30 (.012)	0.35 (.014)
K	0.70 (.028)	0.75 (.030)	0.80 (.031)
L	0.70 (.028)	0.75 (.030)	0.80 (.031)
M	0.375 (.015)	0.425 (.017)	0.475 (.018)

Recommended Pad Layout



Pad Designation

Pad #	Apply	Pad #	Apply
1A	Tip In	4A	Ring Out
1	Tip In	4	Ring Out
2	NC	5	NC
3	Tip Out	6	Ring In
3A	Tip Out	6A	Ring In

NC = Solder to PCB; do not make electrical connection, do not connect to ground.

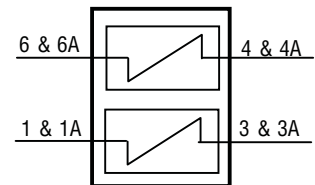
TBU® devices have matte-tin termination finish. Suggested layout should use non-solder mask define (NSMD). Recommended stencil thickness is 0.10-0.12 mm (.004-.005 in.) with stencil opening size 0.025 mm (.0010 in.) less than the device pad size. As when heat sinking any power device, it is recommended that, wherever possible, extra PCB copper area is allowed. For minimum parasitic capacitance, do not allow any signal, ground or power signals beneath any of the pads of the device.

DIMENSIONS: $\frac{\text{MM}}{\text{(INCHES)}}$

Thermal Resistances

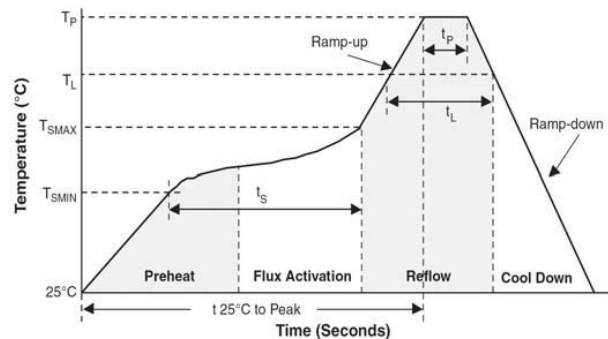
Part #	Symbol	Parameter	Value	Unit
P850-G	$R_{th(j-a)}$	Junction to leads (package)	119	°C/W
		Junction to leads (per TBU® device)	215	°C/W

Block Diagram



Reflow Profile

Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (T_{smax} to T_p)	3 °C/sec. max.
Preheat	
- Temperature Min. (T_{smin})	150 °C
- Temperature Max. (T_{smax})	200 °C
- Time (t_{smin} to t_{smax})	60-180 sec.
Time maintained above:	
- Temperature (T_L)	217 °C
- Time (t_L)	60-150 sec.
Peak/Classification Temperature (T_p)	260 °C
Time within 5 °C of Actual Peak Temp. (t_p)	20-40 sec.
Ramp-Down Rate	6 °C/sec. max.
Time 25 °C to Peak Temperature	8 min. max.



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P850-G Series Dual TBU® High-Speed Protectors

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How to Order

P 850 - G 120 - WH

Form Factor _____

P = Two TBU® protectors in one device

Impulse Voltage Rating _____

850 = 850 V

Directional Indication for Paired Devices _____

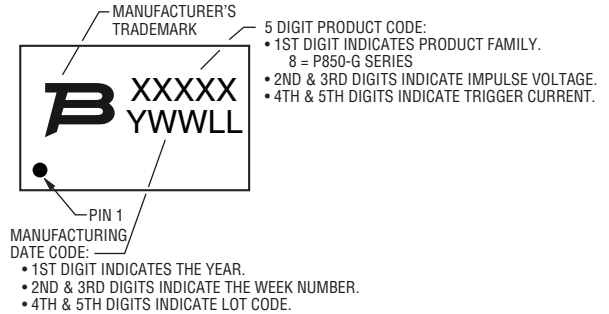
G = Bidirectional

Top Indicator _____

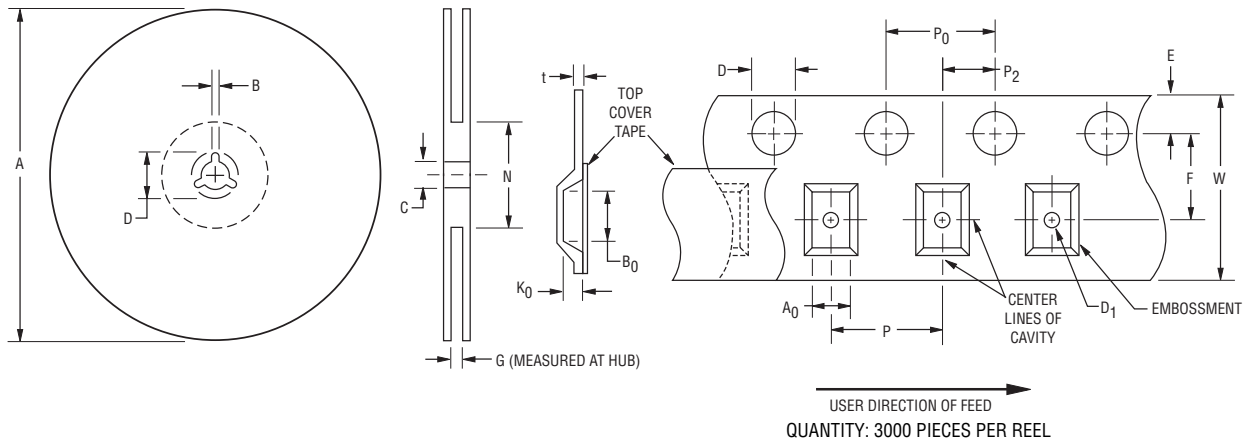
120 = 100 mA

200 = 200 mA

Typical Part Marking



Packaging Specifications (per EIA468-B)



A		B		C		D		G	N
Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Ref.	Ref.
326	330.25	1.5	2.5	12.8	13.5	20.2	-	16.5	102
(12.835)	(13.002)	(.059)	(.098)	(.504)	(.531)	(.795)		(.650)	(4.016)

A ₀		B ₀		D		D ₁		E		F	
Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	max.
4.2	4.4	8.45	8.65	1.5	1.6	1.5	-	1.65	1.85	7.4	7.6
(.165)	(.173)	(.333)	(.341)	(.059)	(.063)	(.059)		(.065)	(.073)	(.291)	(.299)
K ₀		P		P ₀		P ₂		t		W	
Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
1.1	1.3	7.9	8.1	3.9	4.1	1.9	2.1	0.25	0.35	15.7	16.3
(.043)	(.051)	(.311)	(.319)	(.159)	(.161)	(.075)	(.083)	(.010)	(.014)	(.618)	(.642)

DIMENSIONS: $\frac{\text{MM}}{\text{(INCHES)}}$

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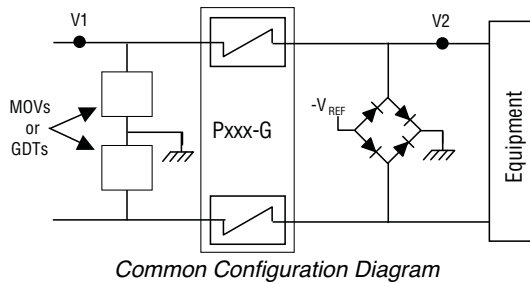
P850-G Series Dual TBU® High-Speed Protectors



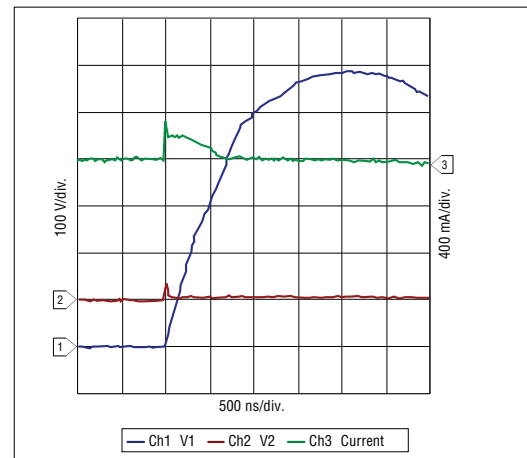
Reference Designs

A cost-effective protection solution combines the Bourns® TBU® protection device with a pair of MOVs or Bourns® GDTs and a diode bridge. The diagram below illustrates a common configuration of these components. The graphs to the right demonstrate the operational characteristics of the circuit.

For new SLIC applications, we recommend that customers evaluate our new TBU-PL series.



P850-G Configuration (ITU-T K.20, K.21, K.20E, K.21E, K.45)			
Product	Qty.	Part Number	Source
TBU® Device	1	P850-G120-WH	Bourns, Inc.
MOV	2	MOV-10D361K	Bourns, Inc.
Diode bridge	2	GSD2004S-V MMBD2004S	Vishay Diodes Inc.



P850-G Solution: 4000 V Lightning 10/700 μsec, 100 A



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REV. 09/15

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